

# Energy Conservation in Memory Hierarchies using Power-Aware Cached-DRAM

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**Abstract.** Main memory has become one of the largest contributors to overall energy consumption and offers many opportunities for power/energy reduction. In this paper, we propose a new memory organization, called Power-Aware Cached-DRAM (PA-CDRAM), that integrates a moderately sized cache directly into a memory device. We use this cache to turn a memory bank off immediately after a memory access to reduce energy consumption. While other work has used CDRAM to improve memory performance, we modify CDRAM to reduce energy consumption. In this paper, we describe our memory organization and describe the challenges for achieving low energy consumption and how to address them. We evaluate the approach using a cycle accurate processor and memory simulator. Our results show that PA-CDRAM achieves an average 28% improvement in the energy-delay product when compared to a time-out power management technique.

**Keywords.** Memory power management, cached DRAM.

## 1 Introduction

Energy consumption is a limiting constraint for both embedded and high performance systems. In embedded systems, the lifetime of a device is limited by the rate of energy dissipation from its battery. On the other hand, energy consumption in high-performance systems increases thermal dissipation, which requires more cooling resources, and has a higher system management overhead. In general, the memory subsystem is considered one of the major energy consumers in computing systems [1]. With the increasing variety of applications that require high memory capacity, a significant increase in the amount of energy consumed in accessing data is expected, which motivates the need for memory energy management schemes.

Memory has a huge internal bandwidth compared to its external bus bandwidth[2]. To exploit the wide internal bus, *cached DRAM* (CDRAM) adds an SRAM cache to the DRAM array on the memory chip [3]. The on-memory cache acts as an extra memory hierarchy level, whose fast access time improves the average memory access time and potentially improves system performance, provided that the on-memory cache is appropriately configured.

In this paper, we explore the benefit of having on-memory cache with respect to its energy consumption. We optimize CDRAM by integrating a moderately sized cache within the chip boundary of a power-aware multi-banked memory. We call this organization *power-aware cached DRAM (PA-CDRAM)*. In addition to improving performance, PA-CDRAM can significantly reduce the energy consumption in external memories by powering off the DRAM banks after the data is transferred to the on-memory cache. We also show that PA-CDRAM is more energy efficient than using an extra level of off-chip cache of equal size.

The remainder of this paper is organized as follows. Section 2 gives an overview of memory technologies and organizations that serve as the base for PA-CDRAM. Section 3 describes the challenges for designing power efficient CDRAM and the design approaches used in PA-CDRAM to overcome them. Evaluation of PA-CDRAM with respect to energy-delay product is presented in Section 4. Section 5 concludes the paper.

## 2 Background

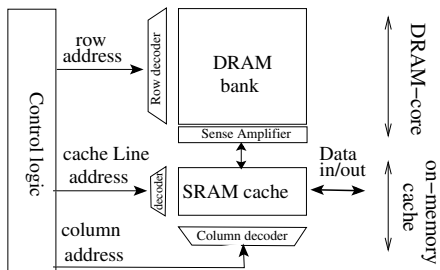
As background for the paper, this section describes the technologies and organizations that serve as the basis for PA-CDRAM.

### 2.1 Embedded DRAM

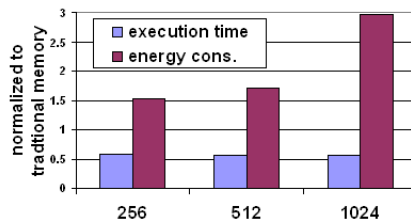
Integrating DRAM and logic cells on the same chip is an attractive solution to achieve both high performance (from logic cells) and high memory density (from DRAM cells). This integration avoids the high latency of going off-chip by doing computation (or even caching) at the memory itself. Currently, manufactured chips with embedded DRAM and logic are mainly used in applications like computer graphics, networking, and handheld devices [4]. Based on the fabrication technology (either DRAM-based or logic-based), some degradation to the speed (density) of the logic (DRAM) cells may occur. For example, in DRAM-based chips, logic cells can be slower by 20% to 35% [4]. However, emerging fabrication technologies aim to overcome these penalties. For example, NEC's embedded DRAM chips offer DRAM-like density with SRAM-like performance [5], and IBM's third generation embedded DRAM chips support two embedded DRAM families for high density and high performance [6].

### 2.2 Cached DRAM

To decrease the average memory access time, Hsu et al. [3] proposed to integrate a small SRAM cache within the memory chip next to the DRAM-core, as shown in Figure 1. Due to high internal bandwidth, large chunks of data can be transferred between the DRAM-core and the on-memory cache with low latency. Average memory access time is improved by accessing the data through the fast on-memory cache rather than the slower DRAM. CDRAM is typically implemented



**Fig. 1.** Functional block diagram of a CDRAM chip



**Fig. 2.** Average performance and energy reduction for different on-memory cache block sizes.

using Synchronous DRAM (*SDRAM*) [7], and each memory bank has its own cache.

While CDRAM improves system performance, it is not designed as a replacement for power-aware memory. Figure 2 shows the average<sup>1</sup> performance and energy consumption of CDRAM versus a traditional memory hierarchy for the same on-memory cache configuration used by Hedge et al. [8]. Each CDRAM chip has a fully associative 4 KB cache. We show the results for different cache block sizes (256, 512 and 1024 bytes). While CDRAM has a good performance improvement over traditional memory, total memory energy suffers dramatically, with an increase of 1.5x to 3.0x. This increase is due to the extra energy consumed from accessing the on-memory caches and transferring more data from the DRAM-core at large block sizes.

### 2.3 Rambus Memories

Rambus [9] is a family of DRAM architectures where the memory bus, the *Rambus Channel*, can operate at high frequencies (800-1600 MHz). As opposed to SDRAM technologies, a single RDRAM chip can service the entire memory request rather than distributing the request to several SDRAM chips. RDRAM chips dynamically transition between power states to reduce the chips' energy consumption. A chip can be set in one of four different power states. The states, in descending order of their power consumption, are: *active*, *standby*, *nap* and *powerdown*. Accessing data requires the chip to be in the active state. The lower the power state of a bank, the longer the synchronization delay needed to switch to the active state to service a request.

## 3 PA-CDRAM

We optimize the CDRAM design to serve as a power-aware memory that is more energy and delay efficient than traditional power-aware memory systems.

<sup>1</sup> running the SPEC2000 benchmarks

We use the CDRAM’s on-chip cache to reduce memory accesses to the DRAM-core; thus, increasing its *idleness*. We use this caching to allow the DRAM-core to be quickly transitioned to a low power state for longer time periods. In using CDRAM as the basis for PA-CDRAM, there are two main challenges that must be addressed: (1) how to configure the DRAM-core’s power management policy, assuming the use of multiple power states; and (2) how to configure the on-memory cache to balance energy and performance. We describe each of these challenges and how we address them below.

### 3.1 DRAM-core power management

To optimize CDRAM operation for energy savings, we need to minimize the number of active chips at any time as well as the duration of active periods. Bounded by the external memory bandwidth, CDRAM (using SDRAM) interleaves data blocks across multiple chips. At each memory request,  $n$  chips within a memory module are activated and each chip provides  $\frac{1}{n}$  of the block size requested. This interleaving of data blocks entails overhead in address decoding, and bit-/word- line activation in more than one chip. Thus, a more energy efficient organization would utilize chips that offer (a) an independent access to the DRAM-array and (b) full bandwidth utilization of the system bus to avoid reducing the memory throughput. The energy overhead is reduced by activating a single chip at each access, and performing fewer address decoding operations in the target chip during data retrieval.

With an on-memory cache, we propose to apply aggressive power management in the DRAM-core to reduce the duration of active periods. During a chip’s idle time, the memory controller can immediately transition the DRAM-core to the sleep state after servicing all outstanding DRAM-core access requests. This is equivalent to the use of a timeout policy with an idle threshold of zero seconds. Although a zero-threshold policy increases the total inactive time, it can degrade performance and increase the total energy consumption when too many requests are directed to a memory chip. The extra delay and energy overheads are due to the transitional cost between power states.

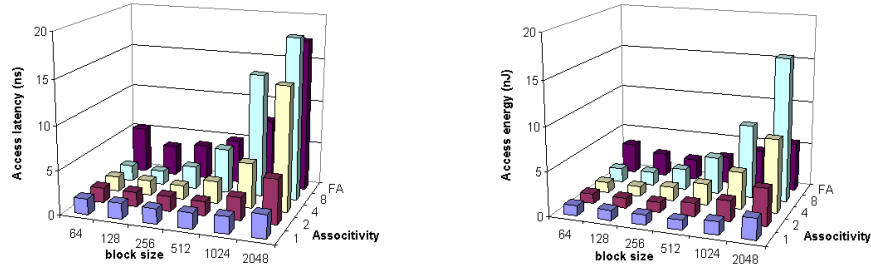
In our PA-CDRAM design, we avoid this problem by choosing the on-memory cache configuration such that it delivers high hit rates while reducing the DRAM-core’s energy consumption. When most data requests are serviced as cache hits in the on-memory cache, the inter-arrival time between requests that reach the DRAM-core increases, making it cost effective to immediately deactivate banks after servicing outstanding requests. We choose to keep the on-memory cache in the active state all the time to avoid delays due to on-demand activation of the cache at each request.

### 3.2 On-memory cache configuration

The on-memory cache miss rate should be kept at a minimum as it directly influences the memory energy consumption (in addition to performance). The higher the miss rate, the more memory energy is consumed due to increased

DRAM-core activity. This energy is consumed in transitioning from the sleep to the active state, performing address decoding, and transferring data. For a given cache size and a fixed number of cache subbanks, the two factors affecting the cache energy consumption and access latency are the *associativity* and the *block size* [10]. We used Cacti-3.0 [10] to study a 256KB cache with respect to latency and energy consumption. Figure 3 shows the trend we observed: compared to n-way associative caches, energy and latency cost *per access* in a fully associative cache decreases at large block sizes, in contrast to small block sizes where full associativity is relatively expensive (in latency and energy). Although we only show the per-access metric for a 256 KB cache, other cache sizes with similar  $\frac{\text{cache size}}{\text{block size}}$  ratios follow the same pattern.

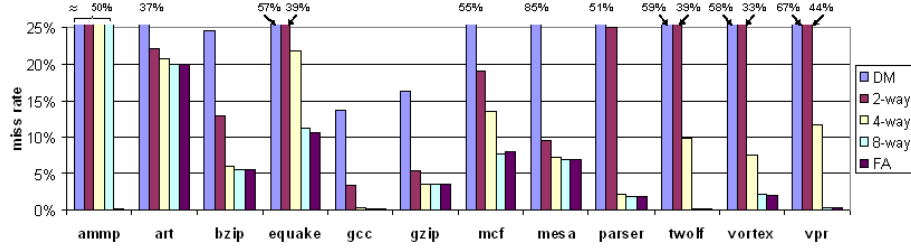
To further examine this issue, we studied a memory with eight CDRAM chips. Each chip contains a cache of moderate size, 256 KB with 512 B cache blocks. Figures 4 and 5 show the effects of varying the associativity and the block size on the on-memory cache average miss rate of the eight chips. We use these results to motivate the selection of our on-memory cache configuration. The miss rates values are collected from the SimpleScalar architecture simulator [11] and correspond to a set of applications from the SPEC2000 (int and fp) benchmarks.



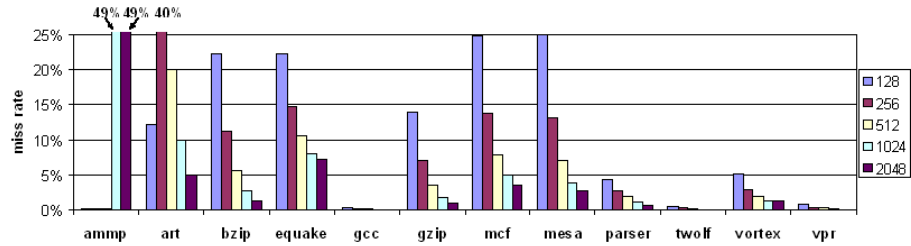
**Fig. 3.** The effect of varying the cache block size and associativity on the cache access latency and energy consumption for a 256KB on-memory cache.

Figure 4 shows that the higher the associativity, the lower the average miss rate across all caches until saturation is reached. Note that, in most of the tested benchmarks, the miss rates of the 8-way set associative caches are as low as the fully associative caches. However, from Figure 3, we see that the per-access latency and energy consumption of a cache with large block sizes (512B and larger) are lower in the fully associative cache than the 8-way cache. From these results, we use fully associative caches with relatively large block sizes as our PA-CDRAM cache configuration.

The performance of on-chip and external caches are constrained by the width of the system bus. To retrieve data from memory with small latencies, the size of the requested blocks are typically small (64 bytes for L2 and 128 bytes for op-



**Fig. 4.** Effect of varying the associativity on the miss rate in caches with 512B blocks.



**Fig. 5.** Effect of varying the cache block size on the miss rate in caches with 512B blocks.

tional L3 caches in some Pentium4 processors [12]). In contrast, the on-memory caches do not have such a constraint because of the large internal memory bandwidth. Thus, large blocks of data can be transferred to the on-memory caches with low latency, which favors the use of large block sizes in PA-CDRAM. Figure 5 shows that on-memory caches with larger blocks have lower miss rates than caches with smaller blocks. With larger transfer sizes, there are fewer accesses to the DRAM-core.

From the energy perspective, Figure 3 shows that for a fixed way-associative cache, accessing large blocks consumes more energy than accessing smaller blocks. However, the energy-per-byte for each access is lower in accessing large blocks. Although the miss rate and the per-byte cache access energy are reduced for large block sizes, there is a potential increase in the memory energy consumption if many unnecessary bytes are transferred between the on-memory cache and the DRAM-core. To achieve a balance between obtaining low miss rates and avoiding excessive memory traffic, we select a relatively large block size around 512B. This is different from the proposal of Koganti et al. [13], which uses block sizes that range from 4KB to 8KB. The difference in our evaluation is that we take into account the energy consumption and delay for accessing the caches (L3 or on-memory). From Figure 3 we conclude that cached DRAM with wide cache lines— although significantly reduces the average on-memory miss rate - is not

energy efficient due to the extra energy consumed in accessing the on-memory cache compared to smaller block sizes in traditional memory hierarchy.

## 4 Evaluation

To evaluate PA-CDRAM, we perform experiments using the SimpleScalar architecture simulator [11] with an integrated memory module [14]. The simulated memory consists of eight chips, each of size 32 MB for a total 256 MB memory.

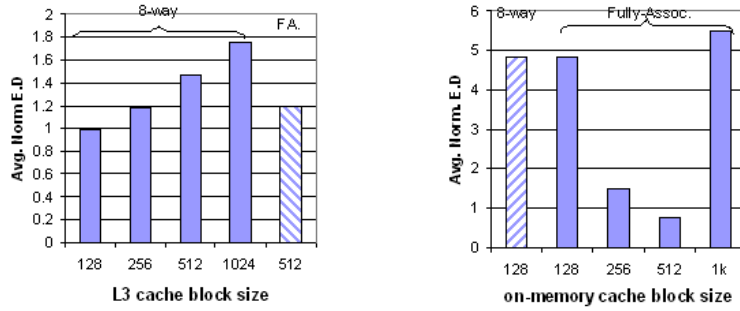
Our study evaluates the energy consumption of PA-CDRAM against a base case that employs traditional power saving policies provided by the Rambus architecture. The base case contains on-chip L1 and L2 caches and an off-chip L3 cache. The size of an L3 cache in the base case is equal to the total size of all eight on-memory caches in PA-CDRAM.

We compute the energy consumption in the DRAM-core, caches and busses. The timing and power characteristics of the simulated RDRAM chip are for the RDRAM 256Mb/1066MHz/32 split bank architecture [9]. Access energy and latency for each cache configuration is obtained using Cacti 3.0 for 130 nm. A delay penalty of 35% is added for accessing logic cells in the memory chip. In the evaluation, we validate the approach for selecting the PA-CDRAM parameters by exploring different on-memory cache configurations and memory time-out thresholds for both the base case and the PA-CDRAM.

We compare the different configurations of the on-memory cache and the DRAM time-out power management policy. We use the energy-delay product to show the most promising configuration across all the tested applications. Figure 6 shows the normalized energy-delay product at different cache configurations. Each data point is the average of 12 benchmarks. We experimented with many cache configurations: we show only the ones with the best results.

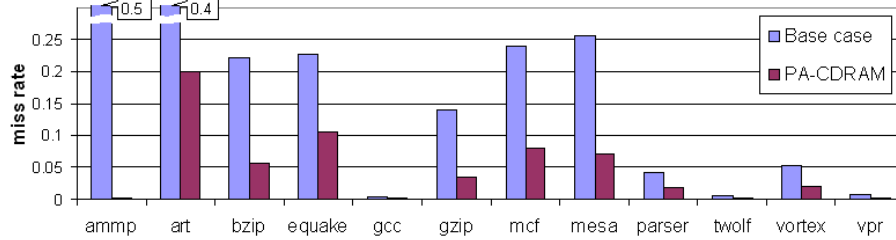
In PA-CDRAM, an on-memory cache with a 512B block size compromise between overall delay and energy consumption. Blocks larger than 512B increase the on-memory cache access costs (both latency and energy) as described in Section 3. On the other hand, reducing the block size increases the DRAM core energy due to the increasing number of DRAM accesses. Similarly, in the base case, a block size of 128B balances energy consumption and overall delay. The figure also show that the best cache configuration in an external cache does not yield the best results when used for an on-memory cache (configurations shown as hashed bars) and visa versa. That is, an 8-way L3 cache with 128B blocks is 5x worse than the 512B fully associative configuration in terms of energy-delay product when used in on-memory caches, while the fully associative 512B configuration is 20% worse than the best L3 configuration. For the remaining results in this evaluation, we explore the benefit of using fully associative on-memory caches with a 512B block size versus an 8-way L3 cache with 128B blocks.

As power management in the DRAM-core relies on increasing idle periods, PA-CDRAM can reduce the memory energy consumption by reducing caches' miss rates. Reducing the on-memory cache miss rates lowers the number of



**Fig. 6.** Average normalized energy-delay product at different cache configurations for base case (left) and PA-CDRAM (right). Data normalized to the base case.

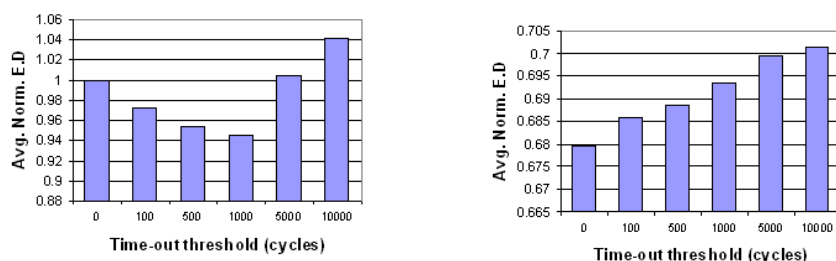
DRAM accesses; thus, reducing the DRAM-core energy. Figure 7 shows the miss rates of L3 in the base case versus the average miss rates of the on-memory caches in PA-CDRAM chips. In all applications, PA-CDRAM reduces the miss rate. This reduction in miss rate is due to both larger blocks and higher associativity in the on-memory caches than in the Large L3 cache.



**Fig. 7.** Miss rates in L3 (base case) versus on-memory (PA-CDRAM) caches.

To show the effect of reducing the miss rate on the choice of proper timeout-policy for the DRAM power management, Figure 8 shows the normalized energy-delay product averaged over the tested applications at different timeout thresholds. The best timeout for the base case is around 1000 cycles. However, for the PA-CDRAM, immediate deactivation of the DRAM-core after each access yields the best overall average energy-delay product. This verifies the result that using an on-memory cache allows aggressive deactivation of the DRAM-core for more efficient memory power management.

In summary, the results shows that PA-CDRAM memory organization, when set with appropriate cache and DRAM-core configuration, can achieve higher energy-delay savings than traditional memory hierarchy.



**Fig. 8.** Average normalized energy-delay product at different timeout-threshold for base case (left) and PA-CDRAM (right). Data normalized to base case.

## 5 Conclusions

In this paper, we described a power-aware cached DRAM organization that reduces both energy consumption and overall delay. While cached DRAM has previously been proposed to improve memory access time, in this paper we explore the energy efficiency of power-aware cached DRAM as an alternative to a traditional power-aware memory. For this, we address the challenges and the trade-offs between maximizing the performance and minimizing energy consumption, and we balance those trade-offs from the DRAM-core and the on-memory caches perspectives. There are many factors affecting energy consumption and performance of a PA-CDRAM memory system. Our evaluation shows that, on average, a fully associative on-memory cache with 512B blocks and memory with immediate transition to lower power state achieves the best energy delay product in the tested benchmarks. When compared to traditional memory using time-out power management, PA-CDRAM reduces the energy-delay product by 28% on average.

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